

TITLE

**FILTER FOR PLASMA DISPLAY PANEL AND METHOD
OF MANUFACTURING THE SAME**

CLAIM OF PRIORITY

[0001] This application makes reference to, incorporates the same herein, and claims all benefits accruing under 35 U.S.C. §119 from an application entitled "*FILTER FOR PLASMA DISPLAY PANEL AND METHOD OF MANUFACTURING THE SAME*" earlier filed in the Korean Intellectual Property Office on 6 November 2002 and thereby duly assigned Serial No. 2002-68385.

BACKGROUND OF THE INVENTION

1. Field of Invention

[0002] The present invention relates to a filter for a plasma display panel and a manufacturing method for making the filter, and more particularly, to a filter for a plasma display panel having a plated mesh pattern for blocking the electromagnetic waves on a surface of a filter substrate, and having a negative photoresist pattern containing additives to avoid reflections of near infrared, neon light, and external light.

2. Description of the Related Art

[0003] Conventionally, a plasma display panel is used for displaying a picture by using a plasma

1 discharging phenomenon. A plasma discharge occurs when a direct or alternate voltage is applied
2 between electrodes of the plasma display panel, and then, resulting in an infrared ray
3 accompanying in the plasma discharging phenomenon causing to a fluorescent substance to emit
4 light.

5 **[0004]** A filter is disposed on an outer surface of such a plasma display panel. The filter performs
6 a few important functions in connection with the operation of the plasma display panel. For
7 example, electromagnetic waves generated when the plasma display panel is working are absorbed
8 by a conductive layer in the composition of the filter, and are electrically grounded. Since the
9 electromagnetic waves are harmful to a human body, the conductive layer for blocking the
10 electromagnetic waves prevents the harmful waves from reaching a user in the vicinity of the
11 plasma display panel. In addition, electromagnetic interference (EMI) radiation including RF radio
12 frequency waves are filtered out. Among other things, these waves could disrupt wireless devices
13 such as radios, television sets and cordless phones in the vicinity of a functioning plasma display
14 panel if these waves were not filtered out.

15 **[0005]** Also, a material coated on the filter absorbs the near infrared rays radiated by the plasma
16 display panel and neon light and rays having a wavelength of about 590 nm. In order to avoid a
17 malfunction of a remote controller when operating the plasma display panel or other electronic
18 devices located around the display, it is desirable to cut off (or block or filter out) these near
19 infrared rays. In addition, it is also preferable to filter out the neon light to improve the quality of
20 an image displayed on the plasma display panel. Neon light is produced in the plasma display
21 panel due to gas discharge. Filtering out this neon light improves the quality of the image. As

1 with many other electronic devices, it is desirable to filter out other unwanted electromagnetic
2 waves, such as RF waves to prevent interference with wireless devices. It is also desirable to filter
3 out other unwanted electromagnetic waves. Also; in order not to degrade the image by reflection
4 of external light, a means for preventing external light from being reflected is mounted on an outer
5 surface of the filter. External light means light in the room and not light generated by the plasma
6 display.

7 [0006] The foregoing method of making the electromagnetic wave shielding layer has a drawback
8 in that the metal mesh, after being formed, must be then attached to the substrate. This attachment
9 process is very risky as the mesh can be easily damaged when attaching it to the substrate. Since,
10 the metal mesh is a very thin layer, handling thereof requires utmost care. However, in spite of
11 carefully handling the metal mesh, the thin layers are easily damaged. Also, the method has
12 another drawback in that it is time consuming and expensive due to the manufacturing of the
13 electromagnetic wave shielding layer itself and the operation of attaching the pretreated films on
14 the front and on back surface of the substrate. Therefore, what is needed is a design for a filter and
15 a method of making the filter that produces an effective filter for the plasma display panel and that
16 the method of making is simple, reliable and inexpensive.

17 SUMMARY OF THE INVENTION

18 [0007] It is therefore an object of the present invention to provide an improved design for a filter
19 for a plasma display panel.

20 [0008] It is also an object to provide a filter for a plasma display panel that is simple, easy and

1 inexpensive to manufacture with a low failure rate during manufacture.

2 **[0009]** It is also an object of the present invention to provide a filter for a plasma display panel that
3 filters out harmful electromagnetic radiation before it reaches a viewer.

4 **[0010]** It is also an object of the present invention to provide a filter for a plasma display panel that
5 filters out near infrared radiation therefore preventing the plasma display panel from degrading the
6 performance of remote control devices in the vicinity of the plasma display panel.

7 **[0011]** It is still an object of the present invention to provide a filter for a plasma display panel that
8 filters out neon light from the plasma display in order to improve image quality of the plasma
9 display unit.

10 **[0012]** It is further an object of the present invention to filter out RF radiation so that the
11 functioning plasma display unit does not interfere with wireless devices near the functioning
12 plasma display unit.

13 **[0013]** It is further an object of the present invention to provide a filter for a plasma display panel
14 that prevents light from within the room from reflecting off the display.

15 **[0014]** It is still an object of the present invention to provide a method of making a filter for a
16 plasma display panel that is inexpensive and reliable.

17 **[0015]** These and other objects can be achieved by a filter for a plasma display having a substrate
18 made out of plastic or glass, having a metallic mesh on one side of the substrate and attached to
19 the substrate, with negative photoresist disposed between gaps in the metallic mesh. The metal
20 mesh is used to block harmful and unwanted electromagnetic waves from emanating from the
21 functioning plasma display. These filtered harmful waves can be RF EMI as well as other

1 electromagnetic waves. The negative photoresist is formed from a material from transparent acryl
2 group or phenol group. The negative photoresist contains additives, including a dye, a pigment
3 and an additive that prevents external light from being reflected. The dye is used to block infrared
4 waves having a wavelength near that of remote controllers, 590 nm or neon light. The dye is
5 preferably an organic compound of an imonium group or a phthalocyanin group. The pigment is
6 preferably an organic compound of the imonium group. The pigment is also used to block near
7 infrared light and neon light produced in the plasma display. The material for preventing the
8 reflection of external light is preferably a metal powder or an inorganic oxide such as TiO_2 or
9 In_2O_3 .

10 [0016] The above structure can be made by the following method. At first, a patterned seed layer
11 of a metal mesh is formed on one side of the substrate. The metal is preferrably sputtered on, then
12 patterned and etched using photoresist. Next, a layer of negative photoresist having the above
13 additives is applied onto the side of the substrate having the metal seed mesh pattern. The negative
14 photoresist is patterned by shining light through the substrate. The patterned seed metal serves as
15 a mask in the patterning of the negative photoresist. The exposed negative photoresist between
16 the metal mesh, is hardened while negative photoresist on the metal is left soft and is then removed
17 to expose the metal. Thus, the patterned negative photoresist pattern complements the metallic
18 pattern. Then, the metal mesh pattern is made thicker by electroplating resulting in the final
19 structure. The patterned negative photoresist and the metal mesh are anywhere from 1 to 50
20 microns thick.

BRIEF DESCRIPTION OF THE DRAWINGS

[0017] A more complete appreciation of the invention, and many of the attendant advantages thereof, will be readily apparent as the same becomes better understood by reference to the following detailed description when considered in conjunction with the accompanying drawings in which like reference symbols indicate the same or similar components, wherein:

[0018] FIG. 1 is a general perspective view of a plasma display panel;

[0019] FIGS. 2A through 2E are general cross-sectional views for describing the method of manufacturing a filter for a plasma display panel, according to the principles of the present invention; and

[0020] FIG. 3 is a flow chart diagram illustrating the sequential steps of the method of manufacturing the filter for a plasma display panel, according to the principles of the present invention.

DETAILED DESCRIPTION OF THE INVENTION

[0021] FIG. 1 is a general perspective view of a plasma display device 100. Referring to FIG. 1, the plasma display device 100 is made up of a image displaying panel 11 a printed circuit substrate 12, which is placed on the backside of the panel 11 and has an electronic device for operating the panel, a filter 14 placed on the front face of the panel 11 and a case 13 accommodating filter 14 therein.

[0022] As illustrated in the magnified drawing A in FIG. 1, the filter 14 is made up of a substrate 16, a film 15 for preventing external light from being reflected attached to a surface of the

substrate 16, an electromagnetic wave shielding layer 17 placed on an opposite side of the substrate 16 and a film 18 for blocking near infrared rays and neon light, attached to the electromagnetic wave shielding layer 17. The electromagnetic wave shielding layer 17 is metallic and is electrically grounded by an electrical connection with the case 13.

[0023] With regard to the filter 14, the substrate 16 is glass or plastic. The electromagnetic wave blocking layer 17 is made of a conductive thin film of copper by pattern etching in a predetermined form, and then, it is treated with a black oxide film to enhance contrast and is then attached on to substrate 16. Alternatively, the electromagnetic wave blocking layer 17 is made of a conductive woven fiber and is then attached to the substrate 16. In order to cut off the near infrared ray and neon light, a film 18 treated with a color for blocking light in a specific wavelength range is used.

[0024] FIGS. 2A through 2E are general cross-sectional views for describing the method of manufacturing a filter for a plasma display panel according to the principles of the present invention. FIG. 3 is a block diagram illustrating the sequential steps of the method of manufacturing the filter for a plasma display panel according to the principles of the present invention. FIGS. 2A through 2E and FIG. 3 will all now be discussed together.

[0025] Referring to FIG. 2A, the whole surface of a substrate 21 is coated with a layer of conductive material 22 for manufacturing the electromagnetic shielding part of the plasma filter. The conductive layer 22 is metallic, and preferably made of a material such as titanium or silver (Ag). The conductive layer 22 will act as a seed layer in an electroplating process to follow. Since the substrate 21 is made of glass or plastic, the formation of a metal layer on the substrate layer so that the metal layer will stick to and not delaminate from the substrate is not easy. Therefore,

1 a coating layer acting as a seed has to be formed thereon before the thickness of the layer can be
2 increased by electroplating. Coating the substrate 21 by the conductive layer 22 can be performed
3 by a commonly used method such as a sputtering method. An operation depicted in FIG. 2A
4 corresponds to step 31 in the flow chart of FIG. 3.

5 **[0026]** Referring to FIG. 2B, a conductive material pattern 23 with a predetermined pattern is
6 formed from the blanket conductive layer 22. The conductive material pattern 23 is formed by a
7 method including coating a positive photoresist, an exposure process using a patterned mask, a
8 development process, an etching process and a photo resist removal process. That is, the positive
9 photoresist is first coated on the whole surface of the conductive layer 22. Then, the positive
10 photoresist is exposed to light through a mask having a predetermined pattern to expose portions
11 of the positive photoresist to form the desired pattern. Thereafter, the exposed portion of the
12 positive photoresist is removed via the developing process. After removing the exposed portion
13 of the positive photoresist, the process of forming the positive photoresist pattern is completed.
14 This method of forming the positive photoresist pattern corresponds to step 32 in FIG. 3.

15 **[0027]** Next, a portion of the conductive layer 22 is removed via the etching process. An etch is
16 performed on the conductive layer with a pattern of positive photoresist formed thereon. Areas
17 of the conductive metal layer not covered by the photoresist are etched all the way to the substrate
18 while portions of the conductive layer that are covered by photoresist are not touched by the
19 etching process. After the etching process, the patterned positive photoresist is removed, leaving
20 only the conductive material pattern 23 on the substrate 21 as depicted in FIG. 2B. This process
21 corresponds to step 33 in FIG. 3.

1 [0028] FIG. 2C is a cross-sectional view illustrating that a negative photoresist 24 is coated on the
2 side of the substrate 21 having the conductive pattern 23. The negative photoresist 24 is made of
3 a material from transparent acryl group or a phenol group. Negative photoresist contains a number
4 of additives, including (1) a dye, (2) a pigment and (3) a material for preventing external light from
5 being reflected off the plasma display panel. It is preferable that all three of these additives are
6 included in the negative photoresist, but the present invention is not limited thereto. The dye is
7 preferably an organic compound of the imonium group or the phthalocyan group. The dye is for
8 blocking out near infrared radiation produced by the plasma display so that it does not interfere
9 with remote control devices. In addition, neon light and light of about 590 nm produced by the
10 functioning plasma display panel is blocked by the dye in the negative photoresist. The pigment
11 is preferably an organic compound of the imonium group. The pigment is also used to block out
12 the near infrared light. The material for preventing external light from being reflected is preferably
13 a metal powder or an inorganic metal oxide such as TiO_2 or In_2O_3 . The step of coating the
14 conductive material pattern 23 on substrate 21 with the negative photoresist 24 containing the
15 additives corresponds to step 34 in FIG. 3.

16 [0029] Unlike positive photoresist, unexposed portions (as opposed to exposed portions in positive
17 photoresist) of negative photoresist are removed during developing. In the present invention, the
18 exposing is preformed by illuminating the side of the substrate 21 that is opposite toe side
19 containing metal pattern 23 or negative photoresist 24. This illuminating light goes through the
20 substrate 21 and through the negative photoresist 24 in spots where there is no metal 23 to block
21 the light. In other words, negative photoresist 24 hardens when it is exposed to light. Therefore,

1 when light is radiated from the opposite side of the negative photoresist coated of the substrate 21
2 as indicated by the arrow B in FIG. 2C, the negative photoresist behind the conductive material
3 pattern 23 will not harden and thus be removed when developed. On the contrary, portions of the
4 negative photoresist 24 not covered by the conductive material pattern 23 will harden and thus not
5 be removed when developed. That is, when light is radiated to the negative photoresist 24, the
6 conductive material pattern 23 serves as a mask. The resulting patterned negative photoresist 25
7 complements the metal pattern 23.

8 **[0030]** FIG. 2D illustrates a completed state of the negative photoresist 25 after exposure and
9 developing. After exposing the blanket negative photoresist 24 to light as described in FIG. 2C,
10 the unhardened (or unexposed) portions of the negative photoresist 24 are removed as depicted in
11 FIG. 2D during developing. Accordingly, only a negative photoresist pattern 25 remains on the
12 substrate 21. The negative photoresist pattern 25 does not overlapping on the conductive material
13 pattern 23. Instead, the resist pattern 25 complements the metal pattern 23. This resist pattern 25
14 remains on the final structure of the filter. The above developed pattern corresponds to step 35
15 in FIG. 3.

16 **[0031]** After the negative photoresist is developed thus exposing the metal pattern 23, the metal
17 pattern 23 is thickened into a mesh by electroplating. FIG. 2E illustrates the thickened metal
18 pattern 23 with the plate mesh 27, corresponding to step 36 in FIG. 3. The substrate 21 formed
19 with the conductive material pattern 23 and a negative photoresist pattern 25 thereon as illustrated
20 in FIG. 2D are immersed in an electrolytic bath for performing the electrical plating. After the
21 electrical plating is finished, a plated mesh 27 is formed on the conductive material pattern 23 and

fills spaces between the negative photoresist pattern 25. A height and a width of the formed metal pattern 23 and plated mesh 27 are preferably from 1 to 50 μm . The metal for the electrical plating is preferably a material having a good conductivity such as silver or copper.

[0032] The filter having the configuration as depicted in FIG. 2E, together with the conductive material pattern 23 and the plated mesh 27 blocks electromagnetic waves that may include RF EMI waves, and the negative photoresist pattern 25 with its additives blocks out neon light and light in a specific wavelength range and prevents the reflection of external light. That is, since the conductive material pattern 23 and the plated mesh 27 are formed of a material having a good conductivity and they are electrically grounded to the case, the electromagnetic waves generated from the plasma display panel can be conducted through the conductive material pattern 23 and the plated mesh 27 and grounded to the case. Also, the dye and the pigment contained in the negative photoresist pattern 25 block out the near infrared rays and neon light produced by the functioning plasma display, and the material for preventing external light from being reflected disperses the external light, thereby preventing the degradation of an image displayed on the plasma display panel.

[0033] The filter for a plasma display panel, according to the present invention, has a metal mesh for blocking the electromagnetic waves and a photoresist pattern for blocking light in a specific wavelength range formed safely on a surface of a substrate. By using the method of making of the present invention, a larger fraction of filters are made satisfactorily with the process of FIGS. 2A through 2E and FIG. 3 versus other processes because the metallic mesh does not have to be attached to the substrate. In other words, fewer filters have to be scraped during the production

1 process. Therefore, the filter has high fidelity in performing its function. Particularly, unlike the
2 design of FIG. 1, the present invention does not employ a plurality of stacked film layers. Thus,
3 production costs are reduced using the method of FIGS. 2A through 2E and FIG. 3. Also, the
4 method of manufacturing the filter according to the present invention has the advantage of easiness
5 in manufacturing in comparison to other methods like that of FIG. 1.

6 **[0034]** While this invention has been particularly illustrated and described with reference to a
7 preferred embodiment thereof, it will be understood by those skilled in the art that various changes
8 in form and details may be made therein without departing from the spirit and scope of the
9 invention as defined by the appended claims. The scope of the invention should, therefore, be
10 determined with reference to the appended claims, along with the full scope of equivalents to
11 which such claims are entitled.